

## PowerMESH™ IGBT, S series 600 V, 13 A low drop

Datasheet - production data

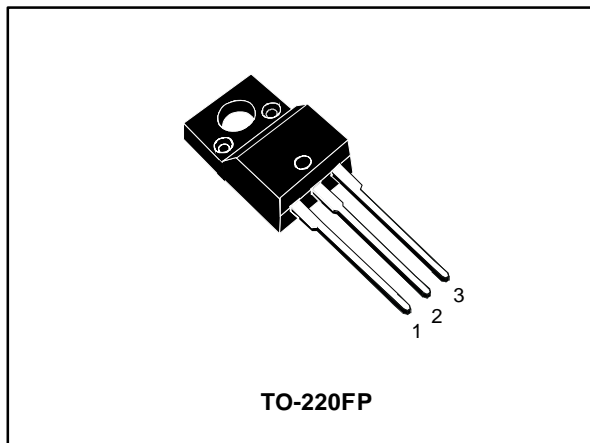
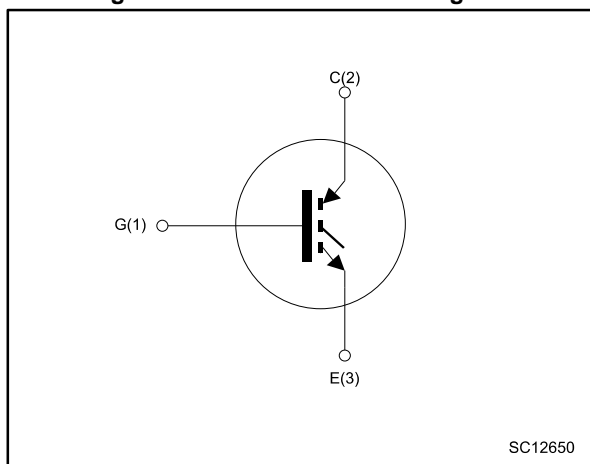


Figure 1: Internal schematic diagram



### Features

- Low on-voltage drop ( $V_{CE(sat)}$ )
- High current capability

### Applications

- Light dimmer
- Static relays
- Motor control

### Description

Using the latest high voltage technology based on a patented strip layout, STMicroelectronics has designed an advanced family of IGBTs, the PowerMESH™ IGBTs, with outstanding performance. The suffix "S" represents a series optimized to achieve minimum on-voltage drop for low frequency applications.

Table 1: Device summary

| Order code  | Marking   | Package  | Packing |
|-------------|-----------|----------|---------|
| STGF20NB60S | GF20NB60S | TO-220FP | Tube    |

**Contents**

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# 1 Electrical ratings

Table 2: Absolute maximum ratings

| Symbol         | Parameter   | Value      | Unit |
|----------------|---|------------|------|
| $V_{CES}$      | Collector-emitter voltage ( $V_{GE} = 0\text{ V}$ )   | 600        | V    |
| $V_{ECS}$      | Emitter-collector voltage ( $V_{GE} = 0\text{ V}$ )   | -20        | V    |
| $V_{GE}$       | Gate-emitter voltage  | $\pm 20$   | V    |
| $I_C$          | Continuous collector current at $T_C = 25\text{ °C}$  | 24         | A    |
|                | Continuous collector current at $T_C = 100\text{ °C}$   | 13         |      |
| $I_{CL}$       | Turn-off latching current   | 70         | A    |
| $I_{CM}^{(1)}$ | Pulsed collector current  | 70         | A    |
| $P_{TOT}$      | Total dissipation at $T_C = 25\text{ °C}$   | 40         | W    |
| $V_{ISO}$      | Insulation withstand voltage (RMS) from all three leads to external heat sink ( $t = 1\text{ s}$ , $T_C = 25\text{ °C}$ ) | 2.5        | kV   |
| $T_{STG}$      | Storage temperature range   | -55 to 150 | °C   |
| $T_J$          | Operating junction temperature  |            |      |

**Notes:**

<sup>(1)</sup>Pulse width limited by safe operating area.

Table 3: Thermal data

| Symbol         | Parameter                           | Value | Unit |
|----------------|-------------------------------------|-------|------|
| $R_{thj-case}$ | Thermal resistance junction-case    | 3.1   | °C/W |
| $R_{thj-amb}$  | Thermal resistance junction-ambient | 62.5  |      |

## 2 Electrical characteristics

$T_C = 25\text{ }^{\circ}\text{C}$  unless otherwise specified

**Table 4: Static characteristics**

| Symbol        | Parameter                            | Test conditions  | Min. | Typ. | Max.      | Unit          |
|---------------|--------------------------------------|--|------|------|-----------|---------------|
| $V_{(BR)CES}$ | Collector-emitter breakdown voltage  | $V_{GE} = 0\text{ V}$ , $I_C = 250\text{ }\mu\text{A}$                                   | 600  |      |           | V             |
| $V_{(BR)ECS}$ | Emitter-collector breakdown voltage  | $V_{GE} = 0\text{ V}$ , $I_C = 10\text{ mA}$   | -20  |      |           |               |
| $I_{CES}$     | Collector cut-off current            | $V_{GE} = 0\text{ V}$ , $V_{CE} = 600\text{ V}$  |      |      | 10        | $\mu\text{A}$ |
|               |                                      | $V_{GE} = 0\text{ V}$ , $V_{CE} = 600\text{ V}$ ,<br>$T_C = 125\text{ }^{\circ}\text{C}$ |      |      | 100       |               |
| $I_{GES}$     | Gate-emitter leakage current         | $V_{CE} = 0\text{ V}$ , $V_{GE} = \pm 20\text{ V}$                                       |      |      | $\pm 100$ | nA            |
| $V_{GE(th)}$  | Gate threshold voltage               | $V_{CE} = V_{GE}$ , $I_C = 250\text{ }\mu\text{A}$                                       | 2.5  |      | 5         | V             |
| $V_{CE(sat)}$ | Collector-emitter saturation voltage | $V_{GE} = 15\text{ V}$ , $I_C = 20\text{ A}$   |      | 1.25 | 1.7       | V             |
|               |                                      | $V_{GE} = 15\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$T_J = 150\text{ }^{\circ}\text{C}$    |      | 1.2  |           |               |

**Table 5: Dynamic characteristics**

| Symbol         | Parameter                    | Test conditions  | Min. | Typ. | Max. | Unit |
|----------------|------------------------------|--|------|------|------|------|
| $g_{fs}^{(1)}$ | Forward transconductance     | $V_{CE} = 10\text{ V}$ , $I_C = 8\text{ A}$  | -    | 20   | -    | S    |
| $C_{ies}$      | Input capacitance            | $V_{CE} = 25\text{ V}$ , $f = 1\text{ MHz}$ ,<br>$V_{GE} = 0\text{ V}$   | -    | 1820 | -    | pF   |
| $C_{oes}$      | Output capacitance           |  | -    | 167  | -    |      |
| $C_{res}$      | Reverse transfer capacitance |  | -    | 27   | -    |      |
| $Q_g$          | Total gate charge            | $V_{CC} = 480\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$ (see <a href="#">Figure 17: "Gate charge test circuit"</a> ) | -    | 83   | 115  | nC   |
| $Q_{ge}$       | Gate-emitter charge          |  | -    | 10   | -    |      |
| $Q_{gc}$       | Gate-collector charge        |  | -    | 27   | -    |      |

**Notes:**

<sup>(1)</sup>Pulse duration= 300  $\mu\text{s}$ , duty cycle 1.5 %

**Table 6: Inductive load switching on characteristics**

| Symbol         | Parameter             | Test conditions  | Min. | Typ. | Max. | Unit             |
|----------------|-----------------------|--|------|------|------|------------------|
| $t_{d(on)}$    | Turn-on delay time    | $V_{CC} = 480\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$ , $R_G = 100\text{ }\Omega$<br>(see <a href="#">Figure 16: "Test circuit for inductive load switching"</a> )                                       | -    | 92   | -    | ns               |
| $t_r$          | Current rise time     |  | -    | 70   | -    | ns               |
| $(di/dt)_{on}$ | Turn-on current slope |  | -    | 340  | -    | A/ $\mu\text{s}$ |
| $t_{d(on)}$    | Turn-on delay time    | $V_{CC} = 480\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$ , $R_G = 100\text{ }\Omega$ ,<br>$T_J = 125\text{ }^{\circ}\text{C}$ (see <a href="#">Figure 16: "Test circuit for inductive load switching"</a> ) | -    | 80   | -    | ns               |
| $t_r$          | Current rise time     |  | -    | 73   | -    | ns               |
| $(di/dt)_{on}$ | Turn-on current slope |  | -    | 320  | -    | A/ $\mu\text{s}$ |

Table 7: Inductive load switching off characteristics

| Symbol         | Parameter             | Test conditions  | Min. | Typ. | Max. | Unit |
|----------------|-----------------------|--|------|------|------|------|
| $t_c$          | Cross-over time       | $V_{CC} = 480\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$ , $R_G = 100\ \Omega$<br>(see <a href="#">Figure 16: "Test circuit for inductive load switching"</a> )                                     | -    | 1.6  | -    | ns   |
| $t_r(V_{off})$ | Off voltage rise time |  | -    | 0.8  | -    |      |
| $t_{d(off)}$   | Turn-off delay time   |  | -    | 1.1  | -    |      |
| $t_f$          | Current fall time     |  | -    | 0.8  | -    |      |
| $t_c$          | Cross-over time       | $V_{CC} = 480\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$ , $R_G = 100\ \Omega$ ,<br>$T_j = 125\text{ }^\circ\text{C}$ (see <a href="#">Figure 16: "Test circuit for inductive load switching"</a> ) | -    | 2.4  | -    | ns   |
| $t_r(V_{off})$ | Off voltage rise time |  | -    | 1.1  | -    |      |
| $t_{d(off)}$   | Turn-off delay time   |  | -    | 2.4  | -    |      |
| $t_f$          | Current fall time     |  | -    | 1.2  | -    |      |

Table 8: Inductive load switching loss characteristics

| Symbol          | Parameter               | Test conditions   | Min. | Typ.  | Max. | Unit |
|-----------------|-------------------------|---|------|-------|------|------|
| $E_{on}^{(1)}$  | Turn-on switching loss  | $V_{CC} = 480\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$ , $R_G = 100\ \Omega$<br>(see <a href="#">Figure 18: "Switching waveform"</a> )                                     | -    | 0.84  | -    | mJ   |
| $E_{off}^{(2)}$ | Turn-off switching loss |   | -    | 7.4   | -    |      |
| $E_{ts}$        | Total switching loss    |   | -    | 8.24  | -    |      |
| $E_{on}^{(1)}$  | Turn-on switching loss  | $V_{CC} = 480\text{ V}$ , $I_C = 20\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$ , $R_G = 100\ \Omega$ ,<br>$T_j = 125\text{ }^\circ\text{C}$ (see <a href="#">Figure 18: "Switching waveform"</a> ) | -    | 0.86  | -    | mJ   |
| $E_{off}^{(2)}$ | Turn-off switching loss |   | -    | 11.5  | -    |      |
| $E_{ts}$        | Total switching loss    |   | -    | 12.36 | -    |      |

**Notes:**

<sup>(1)</sup> $E_{on}$  is the turn-on loss when a external diode is used in the test circuit in [Figure 16: "Test circuit for inductive load switching"](#).

<sup>(2)</sup>Turn-off loss includes the tail of the collector current.

## 2.1 Electrical characteristics (curves)

Figure 2: Output Characteristics

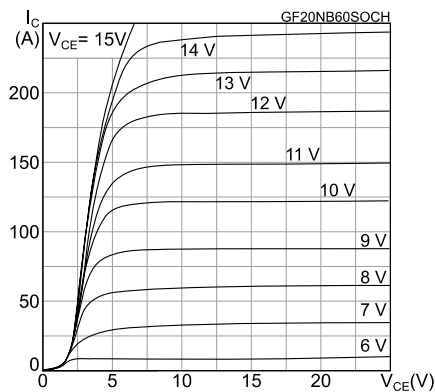


Figure 3: Transfer Characteristics

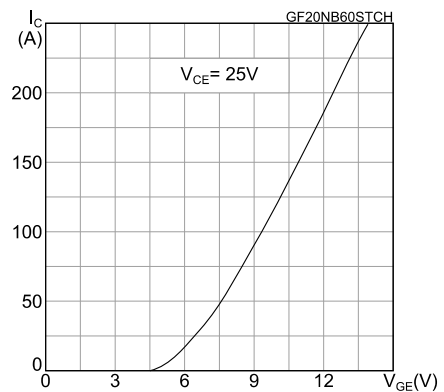


Figure 4: Transconductance

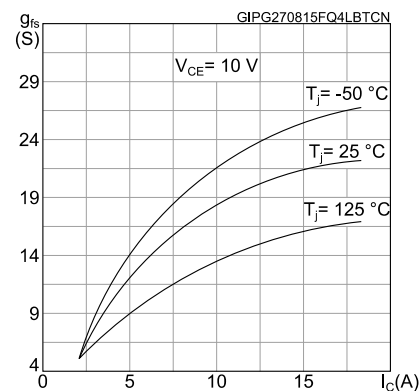


Figure 5: Normalized collector-emitter on voltage vs temperature

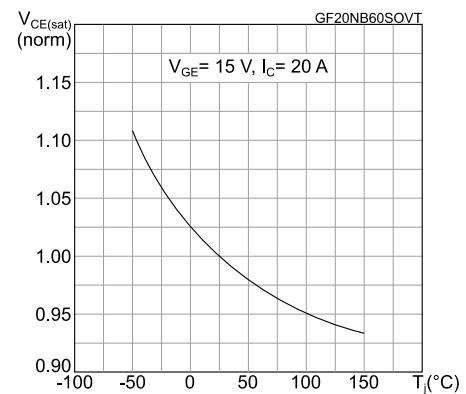


Figure 6: Collector-Emitter on voltage vs collector current

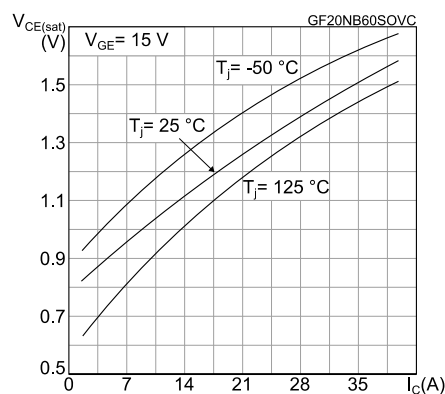
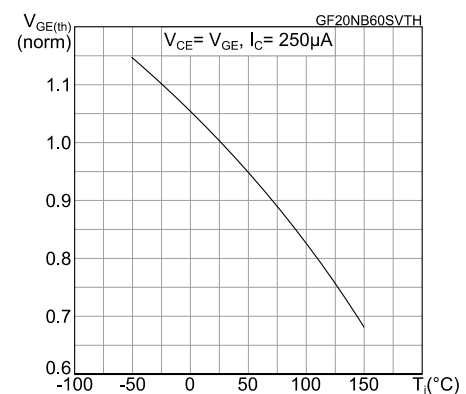


Figure 7: Normalized gate threshold vs temperature



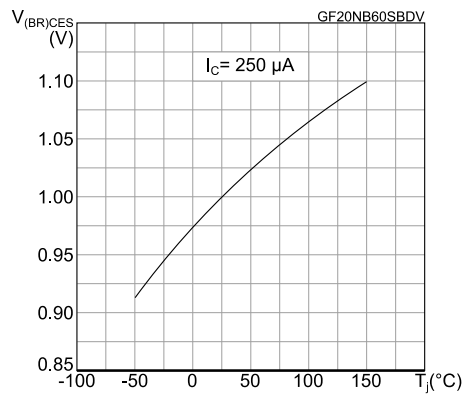
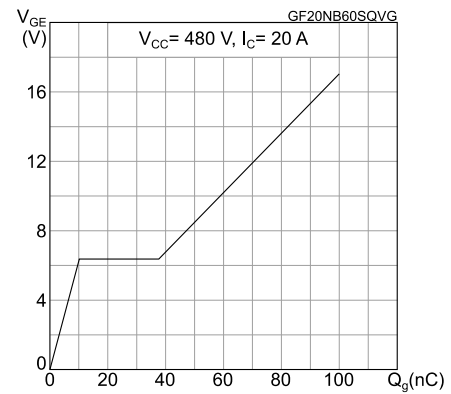
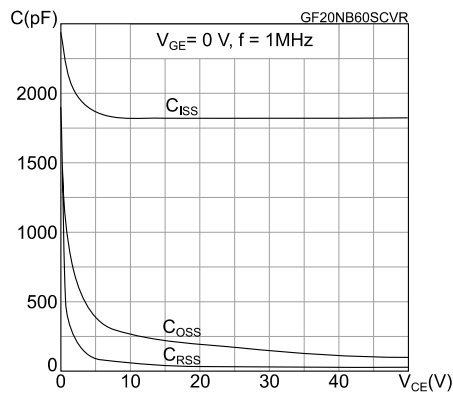
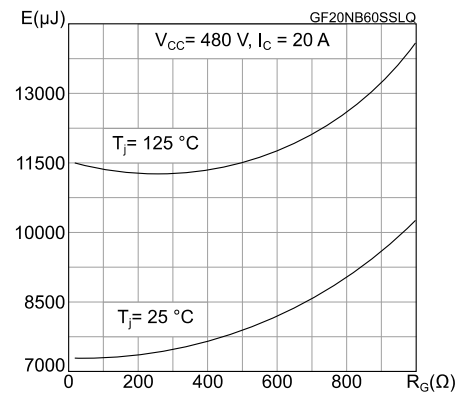
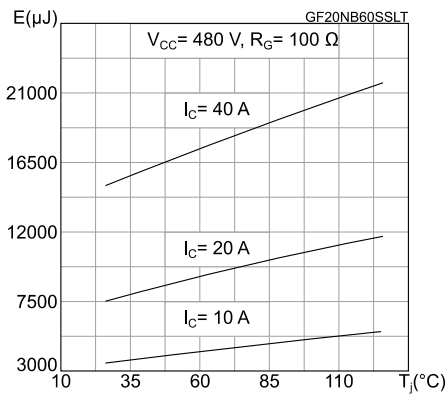
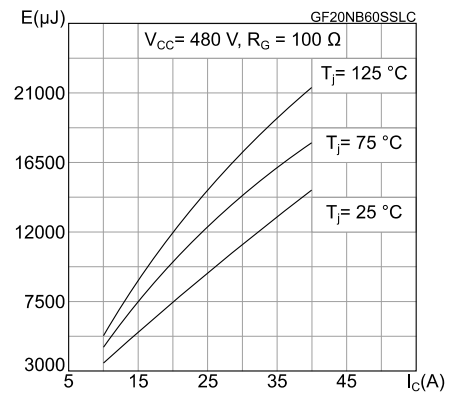
**Figure 8: Normalized breakdown voltage vs temperature****Figure 9: Gate charge vs gate-emitter voltage****Figure 10: Capacitance variations****Figure 11: Switching loss vs gate resistance****Figure 12: Switching loss vs temperature****Figure 13: Switching loss vs collector current**

Figure 14: Thermal impedance

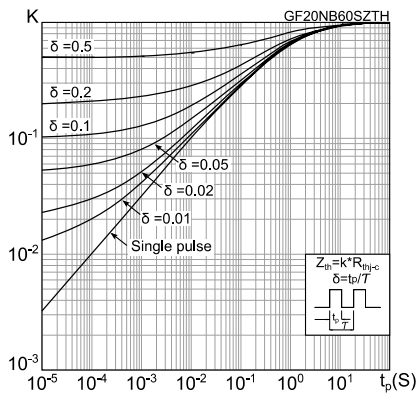
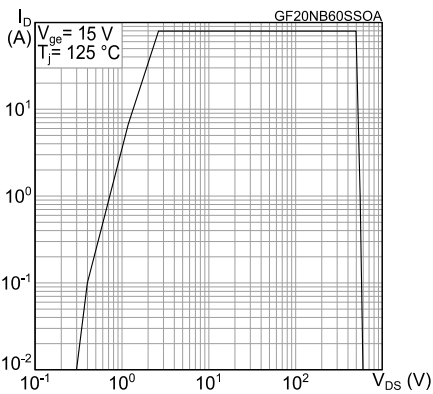


Figure 15: Turn-off SOA





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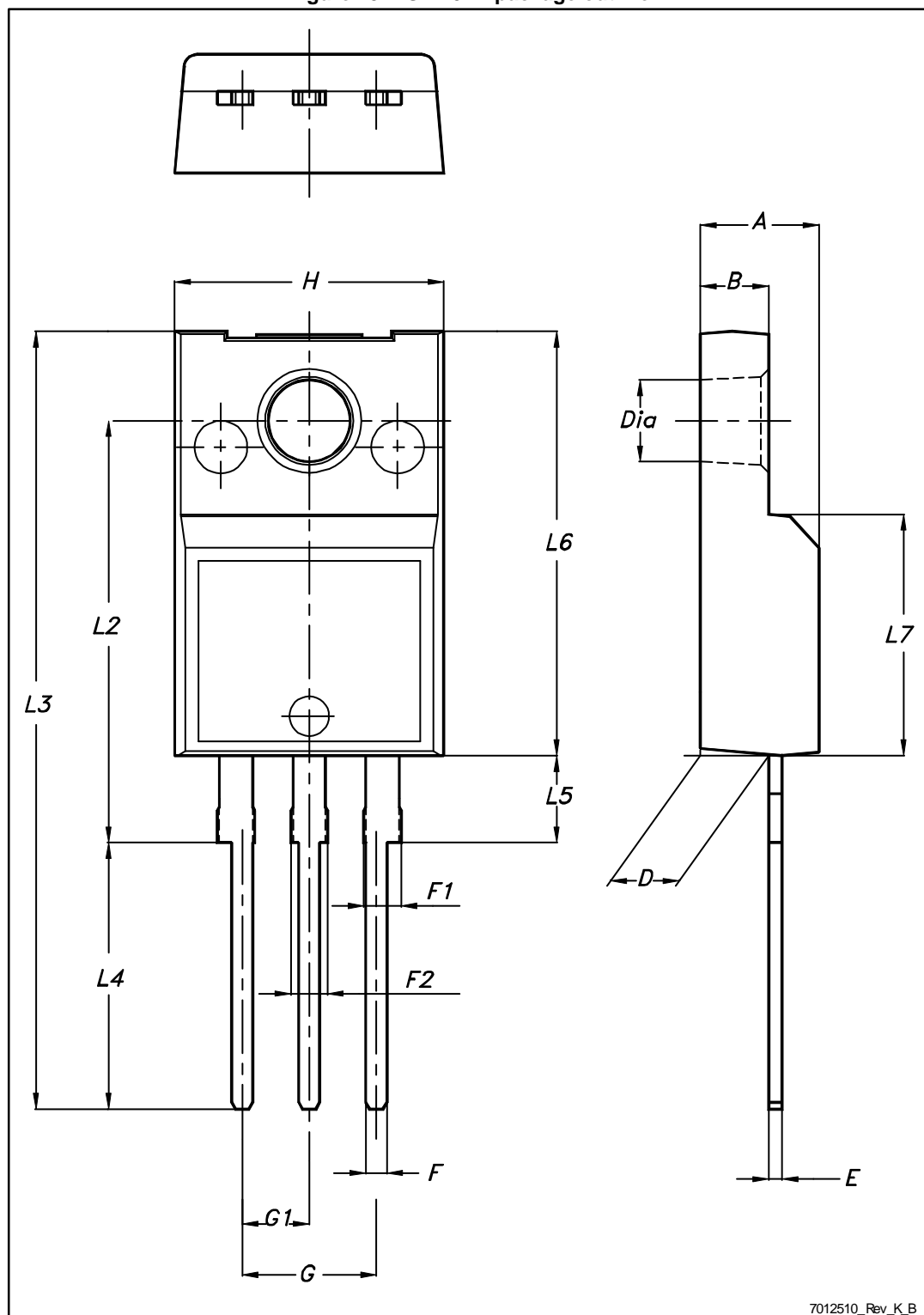
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## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **[www.st.com](http://www.st.com)**. ECOPACK® is an ST trademark.

## 4.1 TO-220FP package information

Figure 19: TO-220FP package outline



7012510\_Rev\_K.B

Table 9: TO-220FP package mechanical data

| Dim. | mm   |      |      |
|------|------|------|------|
|      | Min. | Typ. | Max. |
| A    | 4.4  |      | 4.6  |
| B    | 2.5  |      | 2.7  |
| D    | 2.5  |      | 2.75 |
| E    | 0.45 |      | 0.7  |
| F    | 0.75 |      | 1    |
| F1   | 1.15 |      | 1.70 |
| F2   | 1.15 |      | 1.70 |
| G    | 4.95 |      | 5.2  |
| G1   | 2.4  |      | 2.7  |
| H    | 10   |      | 10.4 |
| L2   |      | 16   |      |
| L3   | 28.6 |      | 30.6 |
| L4   | 9.8  |      | 10.6 |
| L5   | 2.9  |      | 3.6  |
| L6   | 15.9 |      | 16.4 |
| L7   | 9    |      | 9.3  |
| Dia  | 3    |      | 3.2  |

## 5 Revision history

**Table 10: Document revision history**

| Date        | Revision | Changes   |
|-------------|----------|---|
| 17-Dec-2004 | 2        | New template, no content change   |
| 05-Aug-2005 | 3        | Some values changed in table 6  |
| 02-Dec-2015 | 4        | Text and formatting changes throughout document<br>On cover page:<br>- updated Title, Features and Description<br>Added Electrical ratings section heading<br>In section Electrical ratings:<br>- updated tables Absolute Maximum ratings and Thermal Data<br>In section Electrical characteristics:<br>- updated table Static characteristics<br>Added section Package information<br>Updated TO-220FP package information |

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